

RELIABILITY REPORT
FOR
MAX1561ETA
PLASTIC ENCAPSULATED DEVICES

January 22, 2004

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.

SUNNYVALE, CA 94086

Written by



Jim Pedicord
Quality Assurance
Reliability Lab Manager

Reviewed by



Bryan J. Preeshl
Quality Assurance
Executive Director

Conclusion

The MAX1561 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX1561 step-up converter drives up to six white LEDs with a constant current to provide backlight in cell phones, PDAs, and other hand-held devices. The step-up converter topology allows series connection of the white LEDs so the LED currents are identical for uniform brightness. This configuration eliminates the need for ballast resistors and expensive factory calibration.

The MAX1561 includes an internal, high-voltage, low- $R_{DS(ON)}$ N-channel MOSFET switch for high efficiency and maximum battery life. A single Dual Mode™ input provides a simple means of brightness adjustment and on/off control. Fast 1MHz current-mode pulse-width modulated (PWM) operation allows for small input and output capacitors and a small inductor, while minimizing ripple on the input supply/battery. Programmable soft-start eliminates inrush current during startup. The MAX1561 is available in a space-saving, 8-pin, 3mm x 3mm thin QFN package with exposed paddle (EP).

B. Absolute Maximum Ratings

| <u>Item</u> | <u>Rating</u> |
|---|---|
| IN to GND | -0.3V to +6V |
| PGND to GND | -0.3V to +0.3V |
| LX, OUT to GND | -0.3V to +30V |
| CTRL to GND | -0.3V to the lower of +6V or (VIN + 2V) |
| COMP, CS to GND | -0.3 to (VIN + 0.3V) |
| ILX | 1A |
| Operating Temperature Range | -40°C to +85°C |
| Junction Temperature | +150°C |
| Storage Temperature Range | -65°C to +150°C |
| Lead Temperature (soldering, 10s) | +300°C |
| Continuous Power Dissipation (TA = +70°C) | |
| 8-Pin DFN | 1950mW |
| Derates above +70°C | |
| 8-Pin Thin QFN (3mm x 3mm) | 24.4mW/°C |

II. Manufacturing Information

| | |
|----------------------------------|--|
| A. Description/Function: | High-Efficiency, 26V Step-Up Converter for Two to Six White LEDs |
| B. Process: | B8 - Standard 8 micron silicon gate CMOS |
| C. Number of Device Transistors: | 2895 |
| D. Fabrication Location: | California, USA |
| E. Assembly Location: | Thailand |
| F. Date of Initial Production: | December, 2002 |

III. Packaging Information

| | |
|---|---------------------------|
| A. Package Type: | 8-Lead DFN (3x3) |
| B. Lead Frame: | Copper |
| C. Lead Finish: | Solder Plate |
| D. Die Attach: | Silver-filled Epoxy |
| E. Bondwire: | Gold (1.3 mil dia.) |
| F. Mold Material: | Epoxy with silica filler |
| G. Assembly Diagram: | Buildsheet # 05-9000-0073 |
| H. Flammability Rating: | Class UL94-V0 |
| I. Classification of Moisture Sensitivity per JEDEC standard JESD22-A112: | Level 1 |

IV. Die Information

| | |
|----------------------------|---|
| A. Dimensions: | 59 X 79 mils |
| B. Passivation: | Si ₃ N ₄ /SiO ₂ (Silicon nitride/ Silicon dioxide) |
| C. Interconnect: | TiW/ AlCu/ TiWN |
| D. Backside Metallization: | None |
| E. Minimum Metal Width: | .8 microns (as drawn) |
| F. Minimum Metal Spacing: | .8 microns (as drawn) |
| G. Bondpad Dimensions: | 5 mil. Sq. |
| H. Isolation Dielectric: | SiO ₂ |
| I. Die Separation Method: | Wafer Saw |

V. Quality Assurance Information

- A. Quality Assurance Contacts: Jim Pedicord (Manager, Reliability Operations)
Bryan Preeshl (Executive Director of QA)
Kenneth Huening (Vice President)
- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.
0.1% For all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4389 \times 48 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

▲
Temperature Acceleration factor assuming an activation energy of 0.8eV

$$\lambda = 22.62 \times 10^{-9} \quad \lambda = 22.62 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

This low failure rate represents data collected from Maxim's reliability qualification and monitor programs. Maxim also performs weekly Burn-In on samples from production to assure reliability of its processes. The reliability required for lots which receive a burn-in qualification is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on rejects from lots exceeding this level. The Burn-In Schematic (Spec.# 06-6048) shows the static circuit used for this test. Maxim also performs 1000 hour life test monitors quarterly for each process. This data is published in the Product Reliability Report (**RR-1M**) located on the Maxim website at <http://www.maxim-ic.com>.

B. Moisture Resistance Tests

Maxim evaluates pressure pot stress from every assembly process during qualification of each new design. Pressure Pot testing must pass a 20% LTPD for acceptance. Additionally, industry standard 85°C/85%RH or HAST tests are performed quarterly per device/package family.

C. E.S.D. and Latch-Up Testing

The PM76 die type has been found to have all pins able to withstand a transient pulse of $\pm 800\text{V}$, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of $\pm 250\text{mA}$.

Table 1
Reliability Evaluation Test Results

MAX1561ETA

| TEST ITEM | TEST CONDITION | FAILURE IDENTIFICATION | SAMPLE SIZE | NUMBER OF FAILURES |
|-----------------------------------|---|----------------------------------|--------------------|---------------------------|
| Static Life Test (Note 1) | | | | |
| | Ta = 135°C Biased Time = 192 hrs. | DC Parameters & functionality | 48 | 0 |
| Moisture Testing (Note 2) | | | | |
| Pressure Pot | Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs. | DC Parameters & functionality | 77 | 0 |
| 85/85 | Ta = 85°C RH = 85% Biased Time = 1000hrs. | DC Parameters & functionality | 77 | 0 |
| Mechanical Stress (Note 2) | | | | |
| Temperature Cycle | -65°C/150°C 1000 Cycles Method 1010 | DC Parameters & functionality | 77 | 0 |

Note 1: Life Test Data may represent plastic D.I.P. qualification lots.

Note 2: Generic process/package data

Attachment #1

TABLE II. Pin combination to be tested. 1/ 2/

| | Terminal A (Each pin individually connected to terminal A with the other floating) | Terminal B (The common combination of all like-named pins connected to terminal B) |
|----|---|---|
| 1. | All pins except V_{PS1} 3/ | All V_{PS1} pins |
| 2. | All input and output pins | All other input-output pins |

1/ Table II is restated in narrative form in 3.4 below.

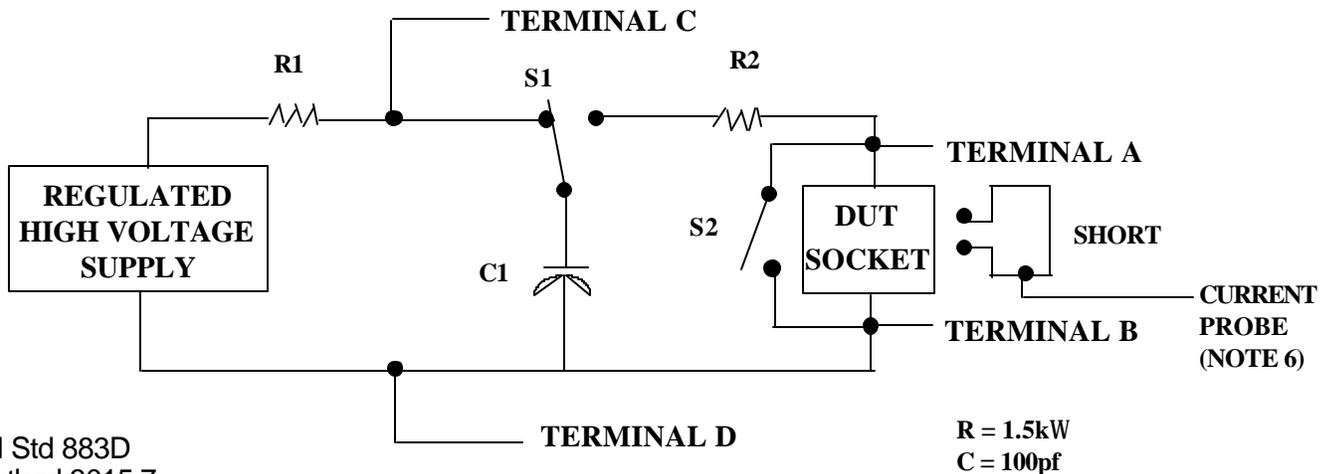
2/ No connects are not to be tested.

3/ Repeat pin combination I for each named Power supply and for ground

(e.g., where V_{PS1} is V_{DD} , V_{CC} , V_{SS} , V_{BB} , GND, $+V_S$, $-V_S$, V_{REF} , etc).

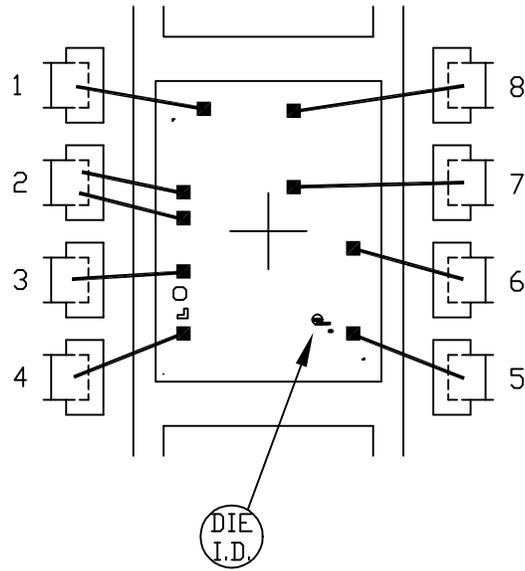
3.4 Pin combinations to be tested.

- a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g., V_{SS1} , or V_{SS2} or V_{SS3} or V_{CC1} , or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
- c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.



3x3x0.8 MM QFN THIN PKG.

EXPOSED PAD PKG.



PKG. CODE: T833-1

SIGNATURES

DATE

MAXIM
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CAV./PAD SIZE:
71x102

PKG.
DESIGN

BOND DIAGRAM #:
05-9000-0073

REV:
B

